2SD2345J

Silicon NPN epitaxial planar type

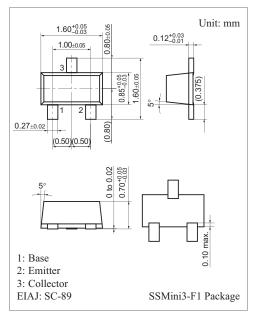
For low frequency amplification

Features

- \bullet High forward current transfer ratio h_{FE}
- Low collector-emitter saturation voltage V_{CE(sat)}
- $\ensuremath{\bullet}$ High emitter-base voltage (Collector open) V_{EBO}
- Low noise voltage NV

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	50	V	
Collector-emitter voltage (Base open)	V _{CEO}	40	V	
Emitter-base voltage (Collector open)	V _{EBO}	15	V	
Collector current	I _C	50	mA	
Peak collector current	I _{CP}	100	mA	
Collector power dissipation	P _C	125	mW	
Junction temperature	Tj	125	°C	
Storage temperature	T _{stg}	-55 to +125	°C	



Marking Symbol: 1Z

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 10 \ \mu A, I_{\rm E} = 0$	50			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm Cl} = 1 \text{ mA}, I_{\rm B} = 0$	40			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$	15			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 20 \text{ V}, I_E = 0$			0.1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CB} = 20 \text{ V}, I_B = 0$			1	μΑ
Forward current transfer ratio *	h _{FE}	$V_{CH} = 10 \text{ V}, I_C = 2 \text{ mA}$	600		2000	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm CI} = 10 \text{ mA}, I_{\rm B} = 1 \text{ mA}$		0.05	0.2	V
Transition frequency	f _T	$V_{CB} = 10 \text{ V}, I_{H} = -2 \text{ mA}, \text{ f} = 200 \text{ MHz}$		120		MHz

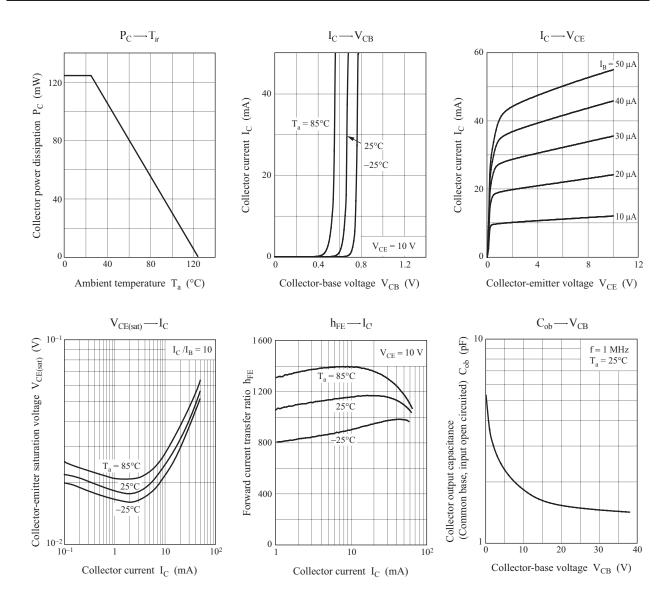
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

Rank	S	Т
$h_{\rm FE}$	600 to 1200	1 000 to 2 000

2SD2345J

Panasonic



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